

LT1783

NOLOGY 1.25MHz, Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amp in SOT-23

reverse supply voltages up to 18V.

below the negative supply.

DESCRIPTION

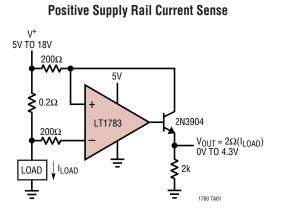
FEATURES

- Operates with Inputs Above V⁺
- Rail-to-Rail Input and Output
- Micropower: 300µA Supply Current Max
- Operating Temperature Range: –40°C to 125°C
- Low Profile (1mm) ThinSOT[™] Package
- Gain Bandwidth product: 1.25MHz
- Slew Rate: 0.42V/µs
- Low Input Offset Voltage: 800µV Max
- Single Supply Input Range: 0V to 18V
- High Output Current: 18mA Min
- Specified on 3V, 5V and ±5V Supplies
- Output Shutdown on 6-Lead Version
- Reverse Battery Protection to 18V
- High Voltage Gain: 1500V/mV

APPLICATIONS

- Portable Instrumentation
- Battery- or Solar-Powered Systems
- Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- MUX Amplifiers
- 4mA to 20mA Transmitters

TYPICAL APPLICATION



The LT1783 can drive loads up to 18mA and still maintain

rail-to-rail capability. A shutdown feature on the 6-lead version can disable the part, making the output high impedance and reducing quiescent current to 5μ A. The LT1783 op amp is available in the 5- and 6-lead SOT-23 packages. For applications requiring lower power, refer to the LT1782.

The LT[®]1783 is a 1.25MHz op amp available in the small

SOT-23 package that operates on all single and split

supplies with a total voltage of 2.5V to 18V. The amplifier

draws less than 300µA of guiescent current and has

reverse battery protection, drawing negligible current for

The input range of the LT1783 includes ground, and a

unique feature of this device is its Over-The-Top[™] opera-

tion capabilitity with either or both of its inputs above the

positive rail. The inputs handle 18V both differential and

common mode, independent of supply voltage. The input

stage incorporates phase reversal protection to prevent

false outputs from occurring even when the inputs are 9V

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25 $V_S = 5V, 0V$ $V_{CM} = 2.5V$ 20 PERCENTAGE OF AMPLIFIERS 15 10 5 0 -900 -600 300 600 900 -300٥ INPUT OFFSET VOLTAGE (µV) 1782 G25

Distribution of Input Offset Voltage



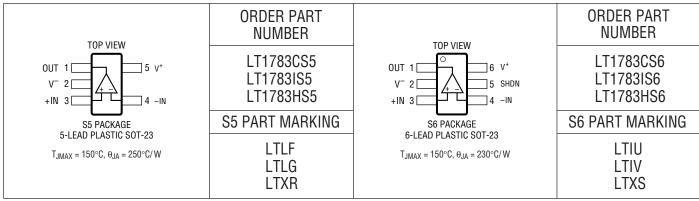
ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V ⁺ to V ⁻)	18V
Input Differential Voltage	
Input Pin Voltage to V ⁻	+24V/-10V
Shutdown Pin Voltage Above V ⁻	18V
Shutdown Pin Current	±10mA
Output Short-Circuit Duration (Note 2)	Indefinite
Operating Temperature Range (Note 3)	
LT1783C	-40°C to 85°C

LII/030	
LT1783I	-40°C to 85°C
	-40°C to 125°C

Specified Temperature Range (Note 4)
LT1783C40°C to 85°C
LT1783I –40°C to 85°C
LT1783H –40°C to 125°C
Junction Temperature 150°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



Consult factory for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = 3V, 0V; V_S = 5V, 0V, V_{CM} = V_{OUT} = half supply, for the 6-lead part V_{PIN5} = 0V, pulse power tested unless otherwise specified. (Note 4)

				LT1	783C/LT1	7831	
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{0S}	Input Offset Voltage	$ \begin{array}{l} T_{A} = 25^{\circ}C \\ 0^{\circ}C \leq T_{A} \leq 70^{\circ}C \\ -40^{\circ}C \leq T_{A} \leq 85^{\circ}C \end{array} $	•		400	800 950 1100	μV μV μV
	Input Offset Voltage Drift (Note 9)		•		2	5	μV/°C
I _{OS}	Input Offset Current	V _{CM} = 18V (Note 5)	•		4	8 7	nA μA
IB	Input Bias Current	V _{CM} = 18V (Note 5) SHDN or V _S = 0V, V _{CM} = 0V to 18V	•		45 35 0.1	80 60	nA μA nA
	Input Bias Current Drift		•		0.06		nA/°C
	Input Noise Voltage	0.1Hz to 10Hz			0.6		μV _{P-P}
en	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.14		pA/√Hz



The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = 3V, 0V; V_S = 5V, 0V, V_{CM} = V_{OUT} = half supply, for the 6-lead part V_{PIN5} = 0V, pulse power tested unless otherwise specified. (Note 4)

					LT1783C/LT1783I				
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS		
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to (V _{CC} – 1V)	•	0.65	1.3 1		ΜΩ GΩ		
		Common Mode, V _{CM} = 0V to 18V	•	0.3	0.5		MΩ		
CIN	Input Capacitance				5		pF		
	Input Voltage Range		•	0		18	V		
CMRR	Common Mode Rejection Ratio (Note 5)	$V_{CM} = 0V$ to $V_{CC} - 1V$ $V_{CM} = 0V$ to 18V (Note 8)	•	90 68	100 80		dB dB		
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	90	100		dB		
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_S = 3V, V_0 = 500 mV \mbox{ to } 2.5V, R_L = 10k \\ V_S = 3V, 0^\circ C \leq T_A \leq 70^\circ C \\ V_S = 3V, -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	200 133 100	1500		V/mV V/mV V/mV		
		$ \begin{array}{l} V_S = 5V, V_0 = 500 mV \ to \ 4.5V, R_L = 10k \\ V_S = 5V, 0^\circ C \leq T_A \leq 70^\circ C \\ V_S = 5V, -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	400 250 200	1500		V/mV V/mV V/mV		
V _{OL}	Output Voltage Swing LOW	No Load $I_{SINK} = 5mA$ $V_{S} = 5V$, $I_{SINK} = 10mA$	•		3 200 330	8 400 600	mV mV mV		
V _{OH}	Output Voltage Swing HIGH	$V_{S} = 3V$, No Load $V_{S} = 3V$, I _{SOURCE} = 5mA	•	2.91 2.6	2.94 2.8		V V		
		$V_S = 5V$, No Load $V_S = 5V$, I _{SOURCE} = 10mA	•	4.91 4.5	4.94 4.74		V V		
I _{SC}	Short-Circuit Current (Note 2)	$V_{S} = 3V$, Short to GND $V_{S} = 3V$, Short to V_{CC}		5 15	10 30		mA mA		
		$V_S = 5V$, Short to GND $V_S = 5V$, Short to V_{CC}		15 20	30 40		mA mA		
	Minimum Supply Voltage		•		2.5	2.7	V		
	Reverse Supply Voltage	I _S = -100μA	•	18			V		
I _S	Supply Current (Note 6)	$\begin{array}{l} 0^{\circ}C \leq T_{A} \leq 70^{\circ}C \\ -40^{\circ}C \leq T_{A} \leq 85^{\circ}C \end{array}$	•		210	300 350 375	μΑ μΑ μΑ		
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 10)	•		5	18	μA		
I _{SHDN}	Shutdown Pin Current	V_{PIN5} = 0.3V, No Load (Note 10) V_{PIN5} = 2V, No Load (Note 10) V_{PIN5} = 5V, No Load (Note 10)	•		0.5 2 5	8	nA μA μA		
	Shutdown Output Leakage Current	V _{PIN5} = 2V, No Load (Note 10)	•		0.05	1	μA		
	Maximum Shutdown Pin Current	V _{PIN5} = 18V, No Load (Note 10)	•		10	30	μA		
VL	Shutdown Pin Input Low Voltage	(Note 10)	•			0.3	V		
V _H	Shutdown Pin Input High Voltage	(Note 10)	•	2			V		
t _{ON}	Turn-On Time	V _{PIN5} = 5V to 0V, R _L = 10k (Note 10)			25		μs		
t _{OFF}	Turn-Off Time	$V_{PIN5} = 0V \text{ to } 5V, R_{L} = 10k \text{ (Note 10)}$			3		μs		
GBW	Gain Bandwidth Product (Note 5)	$ \begin{array}{l} f = 5 kHz \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	750 600 550	1250		kHz kHz kHz		



The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = 3V, 0V; V_S = 5V, 0V, V_{CM} = V_{OUT} = half supply, for the 6-lead part V_{PIN5} = 0V, pulse power tested unless otherwise specified. (Note 4)

					LT1783C/LT1783I		
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
SR	Slew Rate (Note 7)	$ \begin{array}{l} A_V = -1, \ R_L = \infty \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} \end{array} $	•	0.24 0.21 0.019	0.42		V/µs V/µs V/µs
FPBW	Full-Power Bandwidth (Note 11)	$V_{OUT} = 2V_{P-P}$			66		kHz
t _S	Settling Time	V_S = 5V, ΔV_{OUT} = 2V to 0.1%, A_V = -1			12		μs
THD	Distortion	$V_{S} = 3V, V_{0} = 2V_{P-P}, A_{V} = 1, R_{L} = 10k, f = 1kHz$			0.001		%

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = ±5V, V_{CM} = 0V, V_{OUT} = 0V, for the 6-lead part V_{PIN5} = V⁻, pulse power tested unless otherwise specified. (Note 4)

				LT	1783C/LT17	7831	31	
SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS	
V _{OS}	Input Offset Voltage	$ \begin{array}{l} T_A = 25^\circ C \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} \end{array} $	•		500	900 1050 1200	μV μV μV	
	Input Offset Voltage Drift (Note 9)		•		2	5	μV/°C	
I _{OS}	Input Offset Current		•		4	8	nA	
I _B	Input Bias Current		•		40	80	nA	
	Input Bias Current Drift		•		0.06		nA/°C	
	Input Noise Voltage	0.1Hz to 10Hz			1		μV _{P-P}	
e _n	Input Noise Voltage Density	f = 1kHz			20		nV/√Hz	
i _n	Input Noise Current Density	f = 1kHz			0.14		pA/√Hz	
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = -5V to 13V	•	0.65 0.3	1.3 0.5		MΩ MΩ	
CIN	Input Capacitance				5		pF	
	Input Voltage Range		•	-5		13	V	
CMRR	Common Mode Rejection Ratio	$V_{CM} = -5V$ to 13V	•	68	80		dB	
A _{VOL}	Large-Signal Voltage Gain	$ \begin{array}{l} V_0 = \pm 4V, \ R_L = 10k \\ 0^\circ C \leq T_A \leq 70^\circ C \\ -40^\circ C \leq T_A \leq 85^\circ C \end{array} $	•	70 50 40	160		V/mV V/mV V/mV	
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 5mA I _{SINK} = 10mA	•		-4.997 -4.8 -4.67	-4.992 -4.6 -4.4	V V V	
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 5mA I _{SOURCE} = 10mA	•	4.91 4.6 4.5	4.94 4.8 4.74		V V V	
I _{SC}	Short-Circuit Current (Note 2)	Short to GND $0^{\circ}C \le T_A \le 70^{\circ}C$	•	18 15	30		mA mA	
PSRR	Power Supply Rejection Ratio	V _S = ±1.5V to ±9V	•	90	100		dB	
Is	Supply Current	$\begin{array}{l} 0^{\circ}C \leq T_{A} \leq 70^{\circ}C \\ -40^{\circ}C \leq T_{A} \leq 85^{\circ}C \end{array}$	•		230	325 375 400	μΑ μΑ μΑ	
	Supply Current, SHDN	$V_{PIN5} = -3V$, $V_S = \pm 5V$, No Load (Note 10)	•		6	20	μA	
I _{SHDN}	Shutdown Pin Current	V_{PIN5} = -4.7V, V_S = ± 5 V, No Load (Note 10) V_{PIN5} = -3V, V_S = ± 5 V, No Load (Note 10)	•		0.5 2	8	nA μA	



The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are T_A = 25°C. V_S = ±5V, V_{CM} = 0V, V_{OUT} = 0V, for the 6-lead part V_{PIN5} = V⁻, pulse power tested unless otherwise specified. (Note 4)

					LT1	783C/LT17	/831	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS	
	Maximum Shutdown Pin Current	$V_{PIN5} = 9V, V_{S} = \pm 9V$ (Note 10)			10	30	μA	
	Shutdown Output Leakage Current	$V_{PIN5} = -7V$, $V_S = \pm 9V$, No Load (Note 10)	•		0.05	1	μA	
VL	Shutdown Pin Input Low Voltage	V _S = ±5V (Note 10)	•			-4.7	V	
V _H	Shutdown Pin Input High Voltage	V _S = ±5V (Note 10)	•	-2.8			V	
t _{ON}	Turn-On Time	V _{PIN5} = 0V to -5V, R _L = 10k (Note 10)	•		25		μs	
t _{OFF}	Turn-Off Time	$V_{PIN5} = -5V$ to 0V, $R_L = 10k$ (Note 10)	•		3		μs	
GBW	Gain Bandwidth Product		•	800 700 625	1300		kHz kHz kHz	
SR	Slew Rate	$ \begin{array}{l} A_V=-1,\ R_L=\infty,\ V_0=\pm 4V,\ Measured\ at\ V_0=\pm 2V\\ 0^\circ C\leq T_A\leq 70^\circ C\\ -40^\circ C\leq T_A\leq 85^\circ C \end{array} $	•	0.26 0.23 0.21	0.45		V/µs V/µs V/µs	
FPBW	Full-Power Bandwidth (Note 11)	$V_{OUT} = 8V_{P-P}$			18		kHz	
t _S	Settling Time	$\Delta V_{OUT} = 4V$ to 0.1%, $A_V = 1$			10		μs	

The \bullet denotes specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{CM} = V_{OUT} =$ half supply, for the 6-lead part $V_{PIN5} = 0V$, pulse power tested unless otherwise specified. (Note 4)

					LT1783H		
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{OS}	Input Offset Voltage				400	850	μV
			•			3	mV
	Input Offset Voltage Drift (Note 9)		•			15	μV/°C
l _{OS}	Input Offset Current		•			15	nA
		V _{CM} = 18V (Note 5)	•			10	μA
Ι _Β	Input Bias Current		•			150	nA
		V _{CM} = 18V (Note 5)	•			150	μA
	Input Voltage Range		•	0.3		18	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = 0.3V$ to $V_{CC} - 1V$	•	76			dB
		V _{CM} = 0.3V to 18V	•	60			dB
A _{VOL}	Large-Signal Voltage Gain	$V_{S} = 3V, V_{0} = 500 \text{mV}$ to 2.5V, $R_{L} = 10 \text{k}$		200	1500		V/mV
			•	50			V/mV
		$V_{S} = 5V, V_{0} = 500mV$ to 4.5V, $R_{L} = 10k$		400	1500		V/mV
			•	100			V/mV
V _{OL}	Output Voltage Swing LOW	No Load	•			15	mV
		I _{SINK} = 5mA	•			800	mV
		$V_{\rm S} = 5V, I_{\rm SINK} = 10$ mA	•			1200	mV
V _{OH}	Output Voltage Swing HIGH	$V_{\rm S} = 3V$, No Load	•	2.85			V
		$V_{\rm S} = 3V, I_{\rm SOURCE} = 5mA$	•	2.30			V
		$V_{\rm S}$ = 5V, No Load	•	4.85			V
		$V_{\rm S} = 5V, I_{\rm SOURCE} = 10 {\rm mA}$	•	4			V
PSRR	Power Supply Rejection Ratio	$V_{S} = 3V$ to 12.5V, $V_{CM} = V_{0} = 1V$	•	80			dB
	Minimum Supply Voltage		•	2.7			V
	Reverse Supply Voltage	I _S = -100μA	•	18			V



The \bullet denotes specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V; $V_{CM} = V_{OUT} =$ half supply, for the 6-lead part $V_{PIN5} = 0V$, pulse power tested unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1783H TYP	MAX	UNITS
Is	Supply Current		•		210	300 600	μΑ μΑ
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 10)	•			25	μA
I _{SHDN}	Shutdown Pin Current	V _{PIN5} = 0.3V, No Load (Note 10) V _{PIN5} = 2V, No Load (Note 10)	•		0.5	12	nA μA
	Output Leakage Current	V _{PIN5} = 2V, No Load (Note 10)	•			2.5	μA
	Maximum Shutdown Pin Current	V _{PIN5} = 18V, No Load (Note 10)	•			40	μA
GBW	Gain Bandwidth Product	f = 5kHz (Note 5)	•	750 400	1250		kHz kHz
SR	Slew Rate	$A_V = -1, R_L = \infty$ (Note 7)	•	0.24 0.12	0.42		V/µs V/µs

The \bullet denotes specifications which apply over the full operating temperature range of $-40^{\circ}C \le T_A \le 125^{\circ}C$. $V_S = \pm 5V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, $V_{SHDN} = V^-$, $T_A = -40^{\circ}C$ to $125^{\circ}C$, for the 6-lead part $V_{PIN5} = V^-$, pulse power tested unless otherwise specified. (Note 4)

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1783H TYP	MAX	UNITS
V _{OS}	Input Offset Voltage				500	950	μV
			•			3.1	mV
	Input Offset Voltage Drift (Note 9)		•			15	μV/°C
l _{OS}	Input Offset Current		•			15	nA
I _B	Input Bias Current		•			150	nA
CMRR	Common Mode Rejection Ratio	V _{CM} = -4.7V to 13V	•	60			dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 4V, R_L = 10k$	•	70 10	160		V/mV V/mV
V ₀	Output Voltage Swing	No Load		±4.85			V
		$I_{OUT} = \pm 5 m A$	•	±4.20			V
		$I_{OUT} = \pm 10 \text{mA}$	•	±3.80			V
PSRR	Power Supply Rejection Ratio	$V_{S} = \pm 1.5 V \text{ to } \pm 9 V$	•	80			dB
	Minimum Supply Voltage		•	±1.35			V
I _S	Supply Current				230	325	μA
			•			650	μA
	Supply Current, SHDN	$V_{PIN5} = -3V$, $V_S = \pm 5V$, No Load (Note 10)	•			25	μA
I _{SHDN}	Shutdown Pin Current	$V_{PIN5} = -4.7V$, $V_S = \pm 5V$, No Load (Note 10)	•		0.5		nA
		$V_{PIN5} = -3V$, $V_S = \pm 5V$, No Load (Note 10)	•			12	μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 9V, V_{S} = \pm 9V$ (Note 10)	•			45	μΑ
	Output Leakage Current	$V_{PIN5} = -7V$, $V_S = \pm 9V$, No Load	•			3	μA
VL	Shutdown Pin Input Low Voltage	$V_{S} = \pm 5V$	•			-4.7	V
V _H	Shutdown Pin Input High Voltage	$V_{S} = \pm 5V$	•	-2.8			V
GBW	Gain Bandwidth Product	f = 5kHz		800	1300		kHz
			•	425			kHz
SR	Slew Rate	$A_V = -1, R_L = \infty, V_0 = 4V$		0.26	0.45		V/µs
		Measured at $V_0 = \pm 2V$		0.14			V/µs



Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 3: The LT1783C and LT1873I are guaranteed functional over the operating temperature range of -40° C to 85° C. The LT1783H is guaranteed functional over the operating temperature range of -40° C to 125° C.

Note 4: The LT1783C is guaranteed to meet specified performance from 0°C to 70°C. The LT1783C is designed, characterized and expected to meet specified performance from -40°C to 85°C but is not tested or QA sampled at these temperatures. The LT1783I is guaranteed to meet specified performance from -40°C to 85°C. The LT1783H is guaranteed to meet specified performance from -40°C to 125°C.

Note 5: V_S = 5V limits are guaranteed by correlation to V_S = 3V and V_S = ±5V or V_S = ±9V tests.

Note 6: V_S = 3V limits are guaranteed by correlation to V_S = 5V and V_S = \pm 5V or V_S = \pm 9V tests.

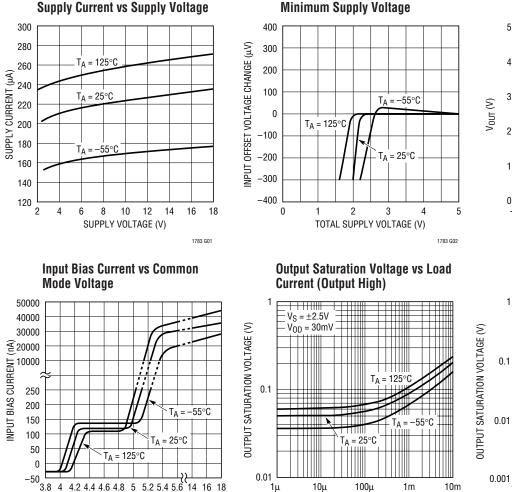
Note 7: Guaranteed by correlation to slew rate at V_S = ± 5 V, and GBW at V_S = 3V and V_S = ± 5 V tests.

Note 8: This specification implies a typical input offset voltage of 1.8mV at V_{CM} = 18V and a maximum input offset voltage of 7.2mV at V_{CM} = 18V. **Note 9:** This parameter is not 100% tested.

Note 10: Specifications apply to 6-lead SOT-23 with shutdown.

Note 11: Full-power bandwidth is calculated from the slew rate. FPBW = $SR/2\pi V_P$.

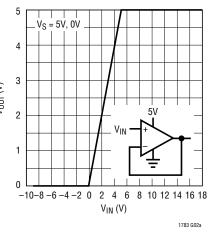
TYPICAL PERFORMANCE CHARACTERISTICS



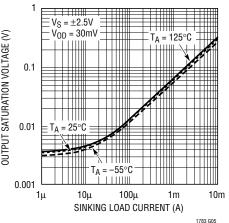
SOURCING LOAD CURRENT (A)

1783 GO4

Output Voltage vs Large Input Voltage



Output Saturation Voltage vs Load Current (Output Low)

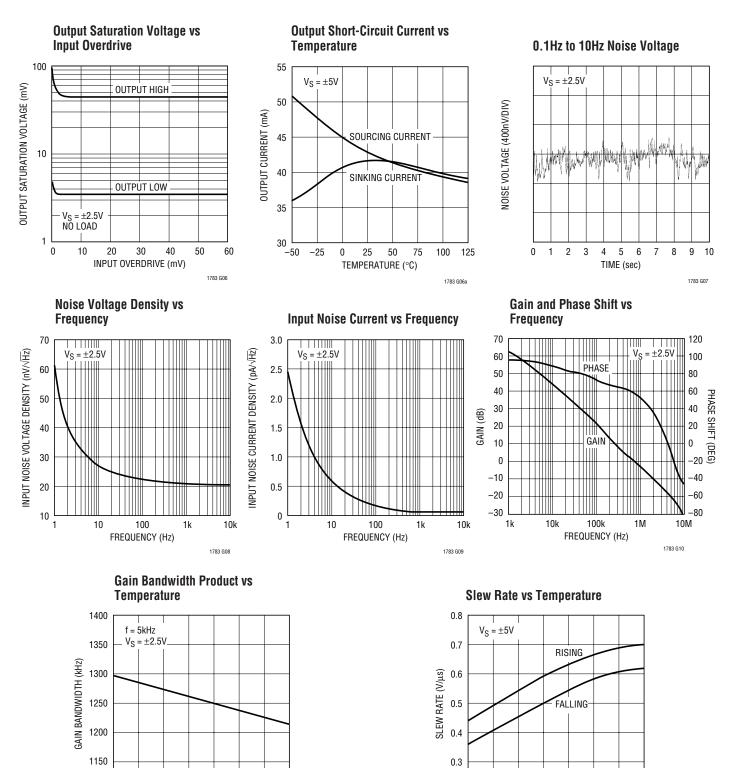




COMMON MODE VOLTAGE (V)

1783 G03

TYPICAL PERFORMANCE CHARACTERISTICS



1783 G11

0.2

-50

-25

0 25 50 75

TEMPERATURE (°C)

100 125

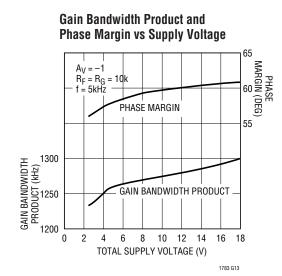
1783 G12

1100

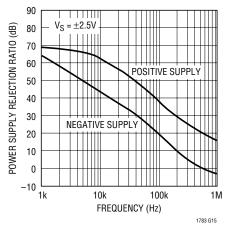
-50 -25 0 25 50 75 100 125

TEMPERATURE (°C)

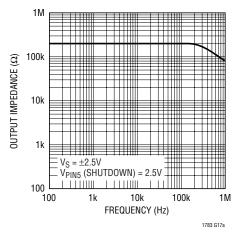
TYPICAL PERFORMANCE CHARACTERISTICS



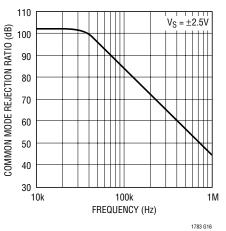
PSRR vs Frequency



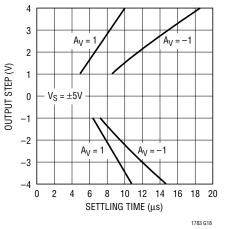
Disabled Output Impedance vs Frequency (Note 8)



CMRR vs Frequency



Settling Time to 0.1% vs Output Step



Output Impedance vs Frequency

100k

1783 G14

Gain Bandwidth and Phase

Margin vs Load Resistance

1400

800

1k

PHASE MARGIN

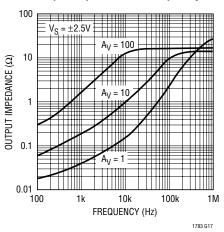
GAIN BANDWIDTH PRODUCT

10k

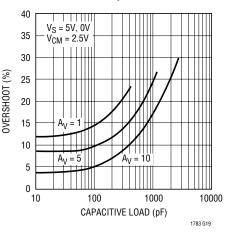
LOAD RESISTANCE (Ω)

V_S = 2.5V

 $A_V = -1$ $R_F = R_G = 10k$ f = 5kHz

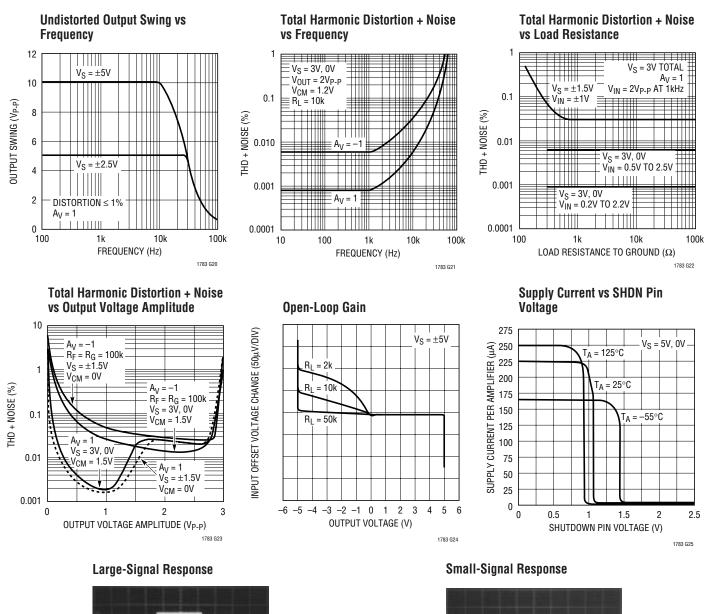


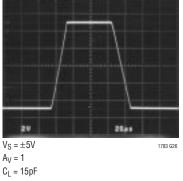
Capacitive Load Handling Overshoot vs Capacitive Load

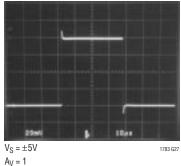




TYPICAL PERFORMANCE CHARACTERISTICS







 $C_L = 15 pF$

APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1783 should be bypassed with a small capacitor (typically 0.1μ F) within an inch of the pin. When driving heavy loads, an additional 4.7μ F electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1783 is protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is less than 1nA.

Inputs

The LT1783 has two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V⁺, the PNP input stage is active and the input bias current is typically -40nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the input bias current is typically 80nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V⁺. The input offset voltage of the NPN stage is untrimmed and is typically 1.8mV.

A Schottky diode in the collector of the input transistors, along with special geometries for these NPN transistors, allow the LT1783 to operate with either or both of its inputs above V⁺. At about 0.3V above V⁺, the NPN input transistor is fully saturated and the input bias current is typically 30μ A at room temperature. The input offset voltage is typically 1.8mV when operating above V⁺. The LT1783 will operate with its inputs 18V above V⁻ regardless of V⁺. The inputs are protected against excursions as much as $10V \text{ below V}^-$ by an internal 1k resistor in series with each input and a diode from the input to the negative supply. The input stage of the LT1783 incorporates phase reversal protection to prevent the output from phase reversing for inputs up to 9V below V⁻. There are no clamping diodes between the inputs and the maximum differential input voltage is 18V.

Output

The output of the LT1783 can swing to within 60mV of the positive rail with no load and within 3mV of the negative rail with no load. When monitoring input voltages within 60mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1783 can sink and source over 30mA at \pm 5V supplies, sourcing current is reduced to 10mA at 3V total supplies as noted in the Electrical Characteristics.

The LT1783 is internally compensated to drive at least 400pF of capacitance under any output loading conditions. A 0.22μ F capacitor in series with a 150Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 10,000pF, at all output currents.

Distortion

There are two main contributors to distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current, and distortion caused by nonlinear common mode rejection. If the op amp is operating inverting, there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V⁺), the CMRR is very good,



APPLICATIONS INFORMATION

typically 100dB. When the LT1783 switches between input stages, there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion but has no effect on the input stage transition distortion. For lowest distortion, the LT1783 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and (V⁺ – 0.8V). See the Typical Performance Characteristics curves, "Total Harmonic Distortion + Noise vs Output Voltage Amplitude."

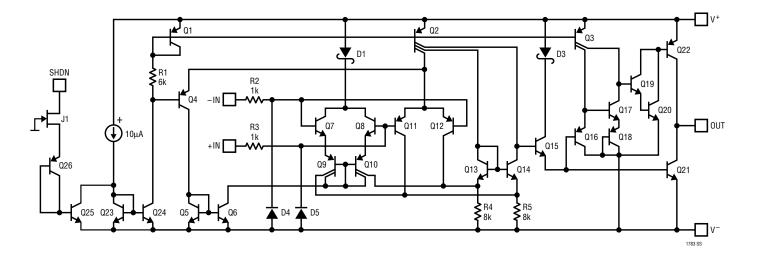
Gain

The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of open-loop gain for various loads shows the details.

Shutdown

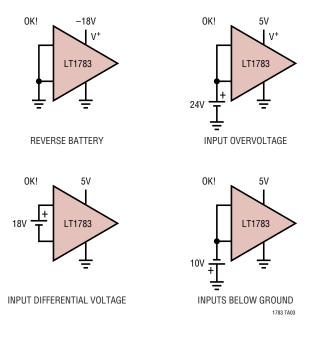
The 6-lead part includes a shutdown feature that disables the part, reducing quiescent current and making the output high impedance. The part can be shut down by bringing the SHDN pin 1.2V or more above V⁻. When shut down, the supply current is about 5µA and the output leakage current is less than 1µA (V⁻ \leq V_{OUT} \leq V⁺). In normal operation, the SHDN pin can be tied to V⁻ or left floating. See the Typical Performance Characteristics curves, "Supply Current vs Shutdown Voltage."







TYPICAL APPLICATION

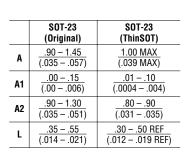


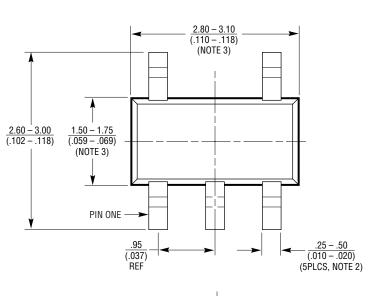
Protected Fault Conditions



PACKAGE DESCRIPTION

S5 Package 5-Lead Plastic SOT-23 (Reference LTC DWG # 05-08-1633) (Reference LTC DWG # 05-08-1635)





1.90

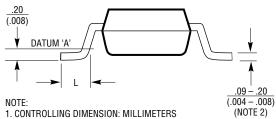
(.074) REF

A1

S5 S0T-23 0401

A2 А

¥



NOTE:

- 1. CONTROLLING DIMENSION: MILLIMETERS
- 2. DIMENSIONS ARE IN $\frac{\text{MILLIMETERS}}{(\text{INCHES})}$

- 3. DRAWING NOT TO SCALE 4. DIMENSIONS ARE INCLUSIVE OF PLATING 5. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR 6. MOLD FLASH SHALL NOT EXCEED .254mm 7. DAGKGOG FUA DEFECTENCY OF 100

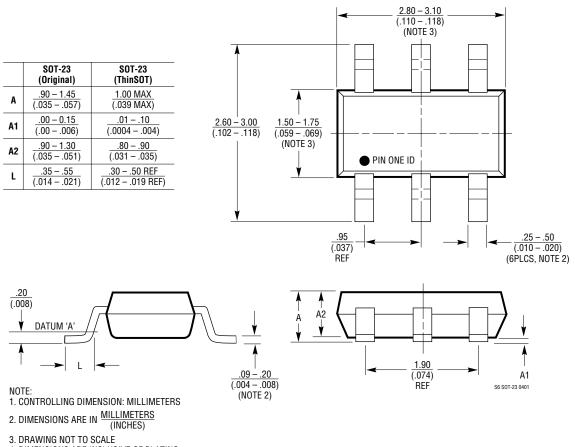
7. PACKAGE EIAJ REFERENCE IS:

SC-74A (EIAJ) FOR ORIGINAL JEDEL MO-193 FOR THIN



PACKAGE DESCRIPTION

S6 Package 6-Lead Plastic SOT-23 (Reference LTC DWG # 05-08-1634) (Reference LTC DWG # 05-08-1636)



4. DIMENSIONS ARE INCLUSIVE OF PLATING

5. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR

6. MOLD FLASH SHALL NOT EXCEED .254mm

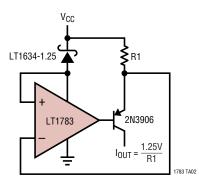
7. PACKAGE EIAJ REFERENCE IS:

SC-74A (EIAJ) FOR ORIGINAL JEDEL MO-193 FOR THIN



TYPICAL APPLICATION

Current Source



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1782	Micropower, Over-The-Top SOT-23 Rail-to-Rail Input and Output Op Amp	SOT-23 Package, Micropower 40 μA per Amplifier, Rail-to-Rail Input and Output , 200kHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: –0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output , 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	55 μ A Supply Current, V _{CM} Extends 44V Above V _{EE} , Independent of V _{CC} , MSOP Package, Shutdown Function
LT1638/LT1639	Dual/Quad, 1.2MHz, 0.4V/µs, Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	170μA Supply Current, Single Supply Input Range: –0.4V to 44V, Rail-to-Rail Input and Output